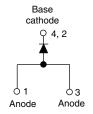


Vishay Semiconductors

Schottky Rectifier, 5.5 A





ו-ח	DΛK	/TO	-252	4 4 1

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I _{F(AV)}	5.5 A				
V_{R}	40 V				
V _F at I _F	See Electrical table				
I _{RM}	40 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	9 mJ				

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable



- · Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$

DESCRIPTION

The VS-50WQ04FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	5.5	A			
V _{RRM}		40	V			
I _{FSM}	t _p = 5 µs sine	340	A			
V _F	5 Apk, T _J = 125 °C	0.44	V			
T _J	Range	- 40 to 150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-50WQ04FNPbF	UNITS			
Maximum DC reverse voltage	V_{R}	40	V			
Maximum working peak reverse voltage	V_{RWM}	40	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 135 °C,	5.5				
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	550	А		
See fig. 7		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	90			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.5 \text{A}, L = 8 \text{mH}$		9	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \text{ x } V_R$ typical		1.2	А		

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VS-50WQ04FNPbF

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
		5 A	T _{.1} = 25 °C	0.51	V		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	1J=25 C	0.63			
See fig. 1	VFM (')	5 A	T _{.1} = 125 °C	0.44			
		10 A	IJ = 125 C	0.59			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V_{R} = Rated V_{R}	3	mA		
See fig. 2	'RM '''	T _J = 125 °C	v _R = nateu v _R	40			
Thereshold voltage	V _{F(TO)}	T T maximum		0.27	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum		26.77	mΩ		
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 10	405	pF			
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 5.0			nH		

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,\,duty\,cycle < 2~\%$

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER SYMBOL TEST CONDITIONS VALUES UNIT							
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W			
Approximate weight			0.3	g			
Approximate weight			0.01	oz.			
Marking device	Case style D-PAK (similar to TO-252AA) 50WQ04		04FN				

Note

(1) $\frac{dP_{tot}}{dT_{\perp}} < \frac{1}{R_{th, \perp A}}$ thermal runaway condition for a diode on its own heatsink



Schottky Rectifier, 5.5 A

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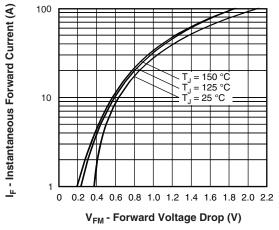


Fig. 1 - Maximum Forward Voltage Drop Characteristics

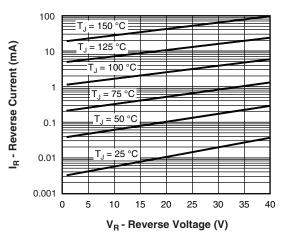


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

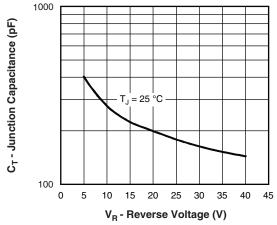


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

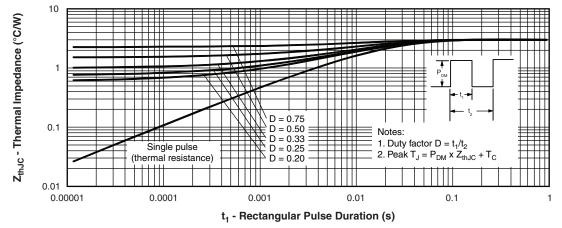


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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Schottky Rectifier, 5.5 A



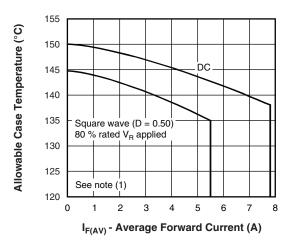


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

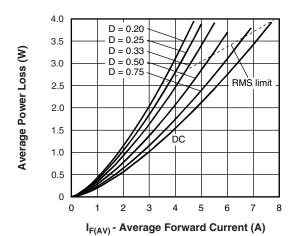
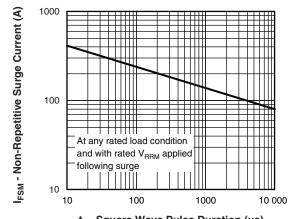


Fig. 6 - Forward Power Loss Characteristics



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

Note

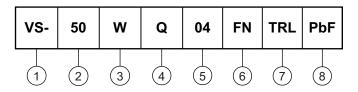
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

Schottky Rectifier, 5.5 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (5.5 A)

3 - Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (04 = 40 V)

6 - FN = TO-252AA (D-PAK)

7 - • None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - PbF = Lead (Pb)-free

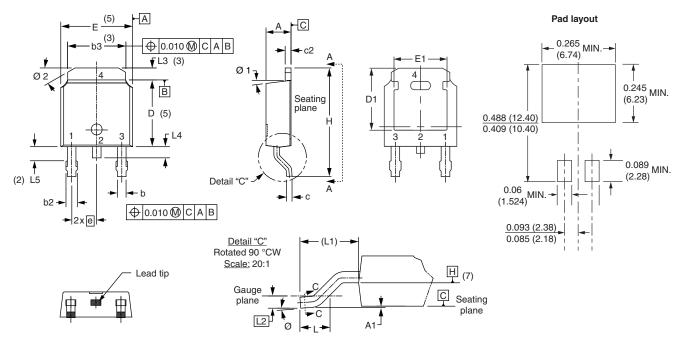
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95016</u>					
Part marking information	www.vishay.com/doc?95059				
Packaging information	www.vishay.com/doc?95033				



Vishay Semiconductors

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	INCHES		5
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		3	
Α	2.18	2.39	0.086	0.094				
A1	-	0.13	-	0.005				
b	0.64	0.89	0.025	0.035				
b2	0.76	1.14	0.030	0.045				
b3	4.95	5.46	0.195	0.215	3			
С	0.46	0.61	0.018	0.024				
c2	0.46	0.89	0.018	0.035				
D	5.97	6.22	0.235	0.245	5			
D1	5.21	-	0.205	-	3			
Е	6.35	6.73	0.250	0.265	5			
E1	4.32	-	0.170	_	3			

SYMBOL	MILLIMETERS		INC	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74	2.74 BSC		0.108 REF.	
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	ı	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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